



Welcome to E-XFL.COM

Understanding [Embedded - Microprocessors](#)

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of [Embedded - Microprocessors](#)

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details

Product Status	Obsolete
Core Processor	PowerPC e300
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	667MHz
Co-Processors/DSP	Communications; QUICC Engine
RAM Controllers	DDR, DDR2
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100/1000Mbps (1)
SATA	-
USB	USB 1.x (1)
Voltage - I/O	1.8V, 2.5V, 3.3V
Operating Temperature	0°C ~ 105°C (TA)
Security Features	-
Package / Case	740-LBGA
Supplier Device Package	740-TBGA (37.5x37.5)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mpc8360zualfg

2.1 Overall DC Electrical Characteristics

This section covers the ratings, conditions, and other characteristics.

2.1.1 Absolute Maximum Ratings

This table provides the absolute maximum ratings.

Table 1. Absolute Maximum Ratings¹

Characteristic		Symbol	Max Value	Unit	Notes
Core and PLL supply voltage for MPC8358 Device Part Number with Processor Frequency label of AD=266MHz and AG=400MHz & QUICC Engine Frequency label of E=300MHz & G=400MHz MPC8360 Device Part Number with Processor Frequency label of AG=400MHz and AJ=533MHz & QUICC Engine Frequency label of G=400MHz		V_{DD} & AV_{DD}	–0.3 to 1.32	V	—
Core and PLL supply voltage for MPC8360 device Part Number with Processor Frequency label of AL=667MHz and QUICC Engine Frequency label of H=500MHz		V_{DD} & AV_{DD}	–0.3 to 1.37	V	—
DDR and DDR2 DRAM I/O voltage	DDR DDR2	GV_{DD}	–0.3 to 2.75 –0.3 to 1.89	V	—
Three-speed Ethernet I/O, MII management voltage		LV_{DD}	–0.3 to 3.63	V	—
PCI, local bus, DUART, system control and power management, I ² C, SPI, and JTAG I/O voltage		OV_{DD}	–0.3 to 3.63	V	—
Input voltage	DDR DRAM signals	MV_{IN}	–0.3 to ($GV_{DD} + 0.3$)	V	2, 5
	DDR DRAM reference	MV_{REF}	–0.3 to ($GV_{DD} + 0.3$)	V	2, 5
	Three-speed Ethernet signals	LV_{IN}	–0.3 to ($LV_{DD} + 0.3$)	V	4, 5
	Local bus, DUART, CLKIN, system control and power management, I ² C, SPI, and JTAG signals	OV_{IN}	–0.3 to ($OV_{DD} + 0.3$)	V	3, 5
	PCI	OV_{IN}	–0.3 to ($OV_{DD} + 0.3$)	V	6

Table 4. MPC8360E TBGA Core Power Dissipation¹ (continued)

Core Frequency (MHz)	CSB Frequency (MHz)	QUICC Engine Frequency (MHz)	Typical	Maximum	Unit	Notes
667	333	500	6.1	6.8	W	2, 3, 5, 9

Notes:

1. The values do not include I/O supply power (OV_{DD} , LV_{DD} , GV_{DD}) or AV_{DD} . For I/O power values, see [Table 6](#).
2. Typical power is based on a voltage of $V_{DD} = 1.2$ V or 1.3 V, a junction temperature of $T_J = 105^\circ\text{C}$, and a Dhrystone benchmark application.
3. Thermal solutions need to design to a value higher than typical power on the end application, T_A target, and I/O power.
4. Maximum power is based on a voltage of $V_{DD} = 1.2$ V, WC process, a junction $T_J = 105^\circ\text{C}$, and an artificial smoke test.
5. Maximum power is based on a voltage of $V_{DD} = 1.3$ V for applications that use 667 MHz (CPU)/500 (QE) with WC process, a junction $T_J = 105^\circ\text{C}$, and an artificial smoke test.
6. Typical power is based on a voltage of $V_{DD} = 1.3$ V, a junction temperature of $T_J = 70^\circ\text{C}$, and a Dhrystone benchmark application.
7. Maximum power is based on a voltage of $V_{DD} = 1.3$ V for applications that use 667 MHz (CPU) or 500 (QE) with WC process, a junction $T_J = 70^\circ\text{C}$, and an artificial smoke test.
8. This frequency combination is only available for rev. 2.0 silicon.
9. This frequency combination is not available for rev. 2.0 silicon.

Table 5. MPC8358E TBGA Core Power Dissipation¹

Core Frequency (MHz)	CSB Frequency (MHz)	QUICC Engine Frequency (MHz)	Typical	Maximum	Unit	Notes
266	266	300	4.1	4.5	W	2, 3, 4
400	266	400	4.5	5.0	W	2, 3, 4

Notes:

1. The values do not include I/O supply power (OV_{DD} , LV_{DD} , GV_{DD}) or AV_{DD} . For I/O power values, see [Table 6](#).
2. Typical power is based on a voltage of $V_{DD} = 1.2$ V, a junction temperature of $T_J = 105^\circ\text{C}$, and a Dhrystone benchmark application.
3. Thermal solutions need to design to a value higher than typical power on the end application, T_A target, and I/O power.
4. Maximum power is based on a voltage of $V_{DD} = 1.2$ V, WC process, a junction $T_J = 105^\circ\text{C}$, and an artificial smoke test.

Table 9. GTX_CLK125 AC Timing Specifications

At recommended operating conditions with $V_{DD} = 2.5 \pm 0.125 \text{ V}$ / $3.3 \text{ V} \pm 165 \text{ mV}$ (continued)

Parameter/Condition	Symbol	Min	Typical	Max	Unit	Notes
GTX_CLK rise and fall time $V_{DD} = 2.5 \text{ V}$ $V_{DD} = 3.3 \text{ V}$	t_{G125R}/t_{G125F}	—	—	0.75 1.0	ns	1
GTX_CLK125 duty cycle GMII & TBI 1000Base-T for RGMII & RTBI	t_{G125H}/t_{G125}	45 47	—	55 53	%	2
GTX_CLK125 jitter	—	—	—	±150	ps	2

Notes:

1. Rise and fall times for GTX_CLK125 are measured from 0.5 and 2.0 V for $V_{DD} = 2.5 \text{ V}$ and from 0.6 and 2.7 V for $V_{DD} = 3.3 \text{ V}$.
2. GTX_CLK125 is used to generate the GTX clock for the UCC Ethernet transmitter with 2% degradation. The GTX_CLK125 duty cycle can be loosened from 47%/53% as long as the PHY device can tolerate the duty cycle generated by GTX_CLK. See [Section 8.2.2, "MII AC Timing Specifications,"](#) [Section 8.2.3, "RMII AC Timing Specifications,"](#) and [Section 8.2.5, "RGMII and RTBI AC Timing Specifications"](#) for the duty cycle for 10Base-T and 100Base-T reference clock.

5 RESET Initialization

This section describes the DC and AC electrical specifications for the reset initialization timing and electrical requirements of the MPC8360E/58E.

5.1 RESET DC Electrical Characteristics

This table provides the DC electrical characteristics for the RESET pins of the device.

Table 10. RESET Pins DC Electrical Characteristics ¹

Characteristic	Symbol	Condition	Min	Max	Unit
Input high voltage	V_{IH}	—	2.0	$OV_{DD} + 0.3$	V
Input low voltage	V_{IL}	—	−0.3	0.8	V
Input current	I_{IN}	—	—	±10	μA
Output high voltage	V_{OH} ²	$I_{OH} = -8.0 \text{ mA}$	2.4	—	V
Output low voltage	V_{OL}	$I_{OL} = 8.0 \text{ mA}$	—	0.5	V
Output low voltage	V_{OL}	$I_{OL} = 3.2 \text{ mA}$	—	0.4	V

Notes:

1. This table applies for pins $\overline{\text{PORESET}}$, $\overline{\text{HRESET}}$, $\overline{\text{SRESET}}$, and $\overline{\text{QUIESCE}}$.
2. $\overline{\text{HRESET}}$ and $\overline{\text{SRESET}}$ are open drain pins, thus V_{OH} is not relevant for those pins.

6.2.2 DDR and DDR2 SDRAM Output AC Timing Specifications

Table 21 and Table 22 provide the output AC timing specifications and measurement conditions for the DDR and DDR2 SDRAM interface.

Table 21. DDR and DDR2 SDRAM Output AC Timing Specifications for Source Synchronous Mode

At recommended operating conditions with GV_{DD} of (1.8 V or 2.5 V) $\pm$ 5%.

Parameter ⁸	Symbol ¹	Min	Max	Unit	Notes
MCK[n] cycle time, (MCK[n]/ $\overline{MCK[n]}$ crossing)	t_{MCK}	6	10	ns	2
Skew between any MCK to ADDR/CMD 333 MHz 266 MHz 200 MHz	t_{AOSKEW}	-1.0 -1.1 -1.2	0.2 0.3 0.4	ns	3
ADDR/CMD output setup with respect to MCK 333 MHz 266 MHz 200 MHz	t_{DDKHAS}	2.1 2.8 3.5	—	ns	4
ADDR/CMD output hold with respect to MCK 333 MHz 266 MHz—DDR1 266 MHz—DDR2 200 MHz	t_{DDKHAX}	2.0 2.7 2.8 3.5	—	ns	4
$\overline{MCS}(n)$ output setup with respect to MCK 333 MHz 266 MHz 200 MHz	t_{DDKHCS}	2.1 2.8 3.5	—	ns	4
$\overline{MCS}(n)$ output hold with respect to MCK 333 MHz 266 MHz 200 MHz	$t_{DDKHCSX}$	2.0 2.7 3.5	—	ns	4
MCK to MDQS	t_{DDKMH}	-0.8	0.7	ns	5, 9
MDQ/MECC/MDM output setup with respect to MDQS 333 MHz 266 MHz 200 MHz	t_{DDKHDS} , t_{DDKLDS}	0.7 1.0 1.2	—	ns	6
MDQ/MECC/MDM output hold with respect to MDQS 333 MHz 266 MHz 200 MHz	t_{DDKHDX} , t_{DDKLDX}	0.7 1.0 1.2	—	ns	6
MDQS preamble start	t_{DDKHMP}	$-0.5 \times t_{MCK} - 0.6$	$-0.5 \times t_{MCK} + 0.6$	ns	7

This figure provides the AC test load for the DDR bus.

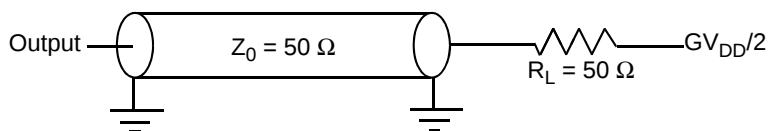


Figure 8. DDR AC Test Load

Table 22. DDR and DDR2 SDRAM Measurement Conditions

Symbol	DDR	DDR2	Unit	Notes
V_{TH}	$MV_{REF} \pm 0.31 V$	$MV_{REF} \pm 0.25 V$	V	1
V_{OUT}	$0.5 \times GV_{DD}$	$0.5 \times GV_{DD}$	V	2

Notes:

1. Data input threshold measurement point.
2. Data output measurement point.

This figure shows the DDR SDRAM output timing diagram for source synchronous mode.

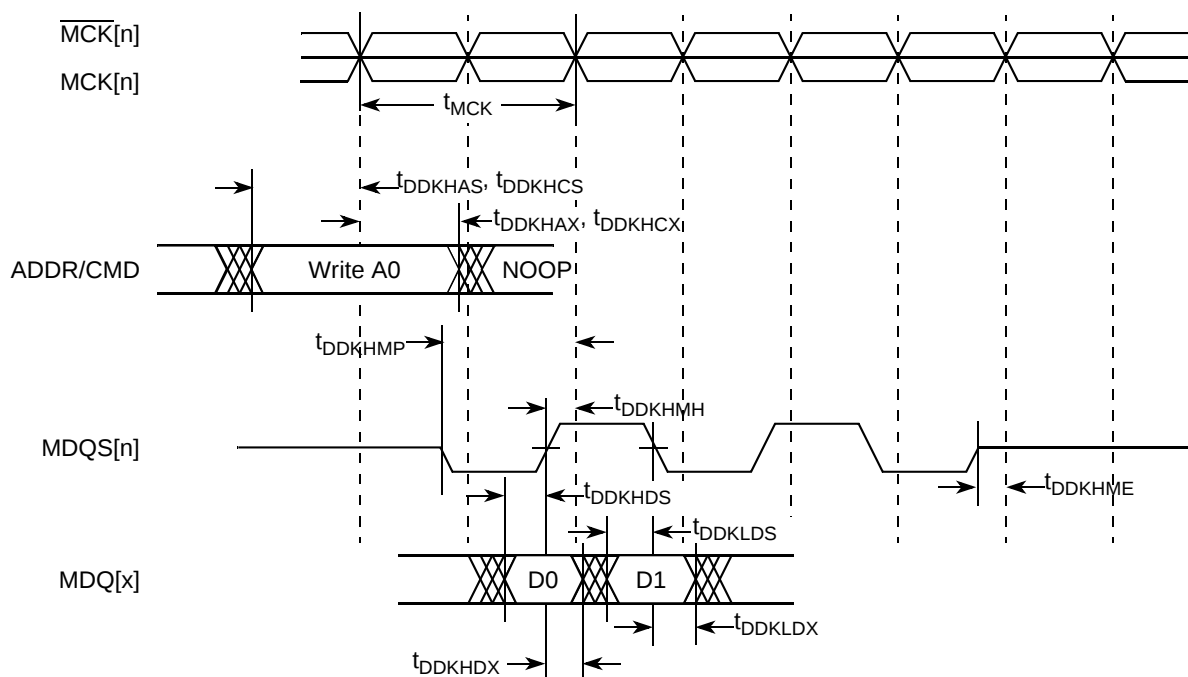


Figure 9. DDR SDRAM Output Timing Diagram for Source Synchronous Mode

8.3.2 MII Management AC Electrical Specifications

This table provides the MII management AC timing specifications.

Table 37. MII Management AC Timing Specifications

At recommended operating conditions with V_{DD} is 3.3 V $\pm$ 10%.

Parameter/Condition	Symbol ¹	Min	Typ	Max	Unit	Notes
MDC frequency	f_{MDC}	—	2.5	—	MHz	2
MDC period	t_{MDC}	—	400	—	ns	—
MDC clock pulse width high	t_{MDCH}	32	—	—	ns	—
MDC to MDIO delay	$t_{MDTKHDX}$ $t_{MDTKHDV}$	10 —	—	— 110	ns	3
MDIO to MDC setup time	$t_{MDRDVKH}$	10	—	—	ns	—
MDIO to MDC hold time	$t_{MDRDXXKH}$	0	—	—	ns	—
MDC rise time	t_{MDCR}	—	—	10	ns	—
MDC fall time	t_{MDHF}	—	—	10	ns	—

Notes:

1. The symbols used for timing specifications follow the pattern of $t_{(first\ two\ letters\ of\ functional\ block)(signal)(state)(reference)(state)}$ for inputs and $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$ for outputs. For example, t_{MDKHDX} symbolizes management data timing (MD) for the time t_{MDC} from clock reference (K) high (H) until data outputs (D) are invalid (X) or data hold time. Also, $t_{MDRDVKH}$ symbolizes management data timing (MD) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{MDC} clock reference (K) going to the high (H) state or setup time. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
2. This parameter is dependent on the csb_clk speed (that is, for a csb_clk of 267 MHz, the maximum frequency is 8.3 MHz and the minimum frequency is 1.2 MHz; for a csb_clk of 375 MHz, the maximum frequency is 11.7 MHz and the minimum frequency is 1.7 MHz).
3. This parameter is dependent on the ce_clk speed (that is, for a ce_clk of 200 MHz, the delay is 90 ns and for a ce_clk of 300 MHz, the delay is 63 ns).

This figure shows the MII management AC timing diagram.

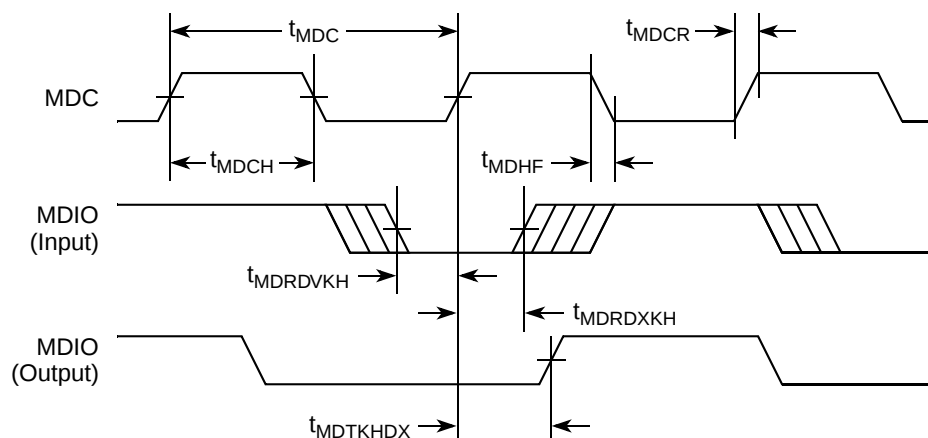
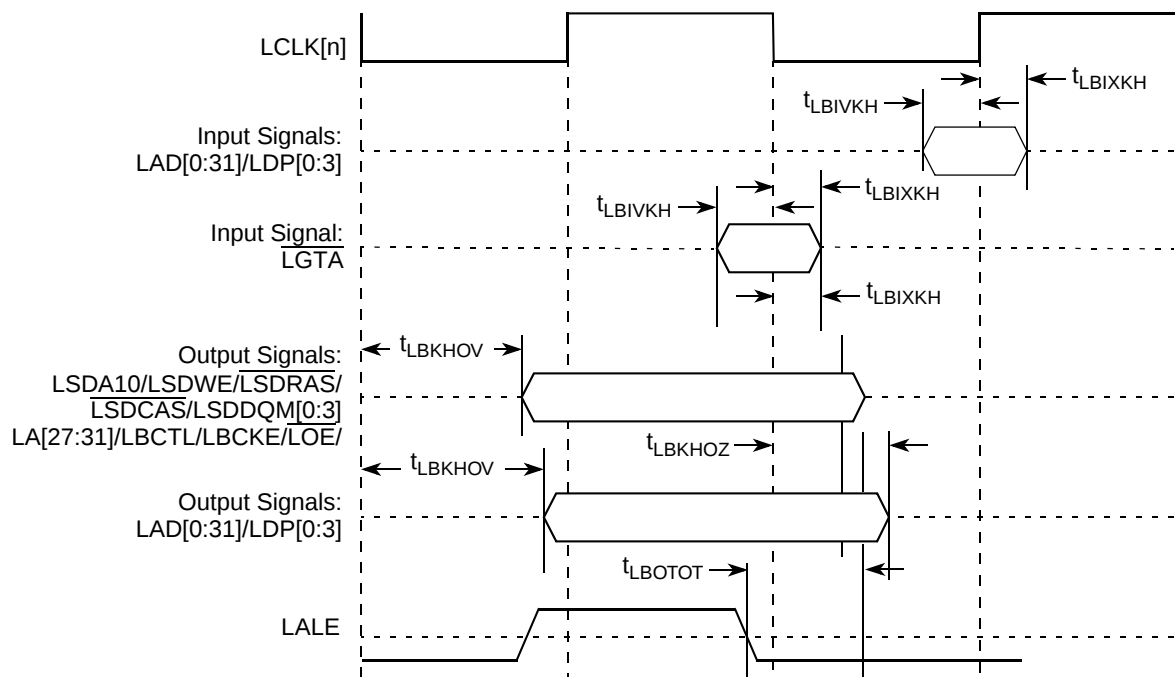
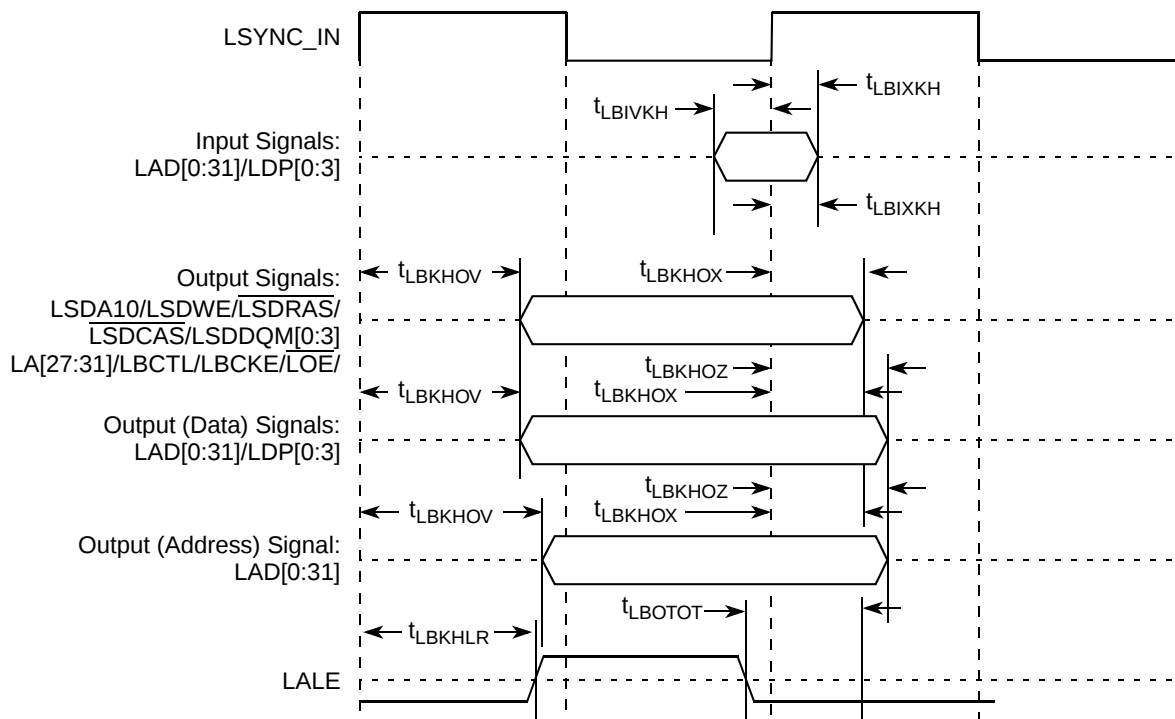


Figure 21. MII Management Interface Timing Diagram

These figures show the local bus signals.



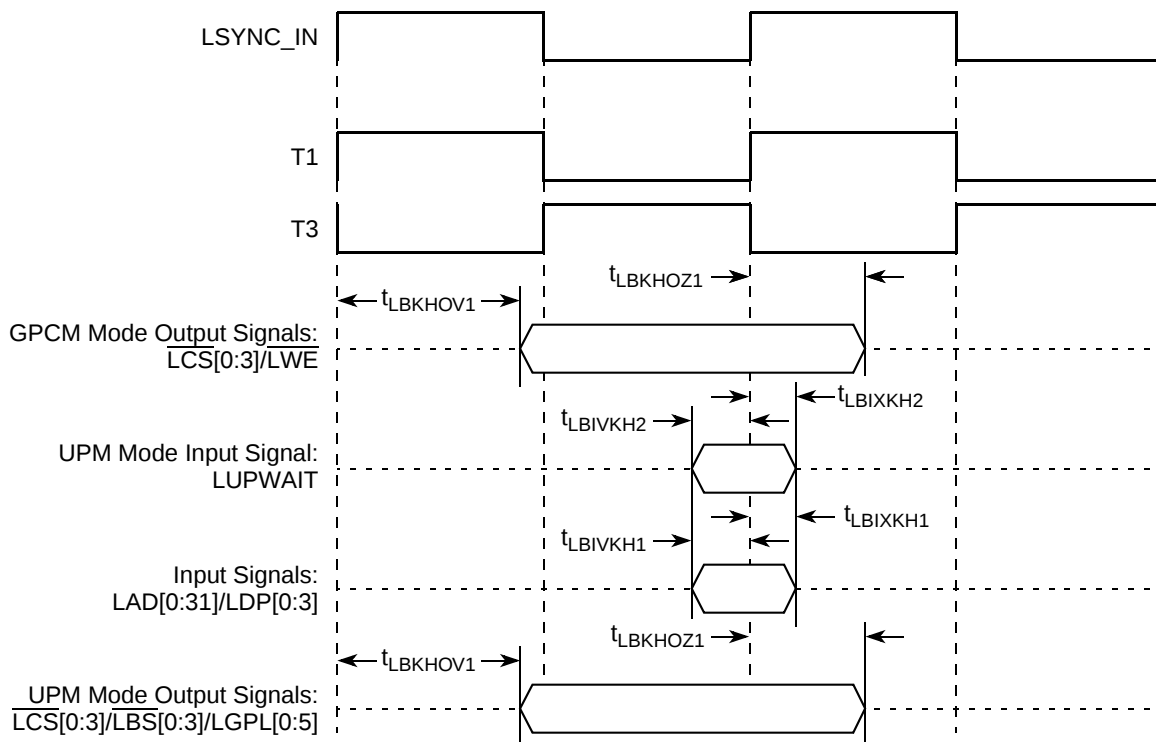


Figure 25. Local Bus Signals, GPCM/UPM Signals for LCRR[CLKDIV] = 2 (DLL Enabled)

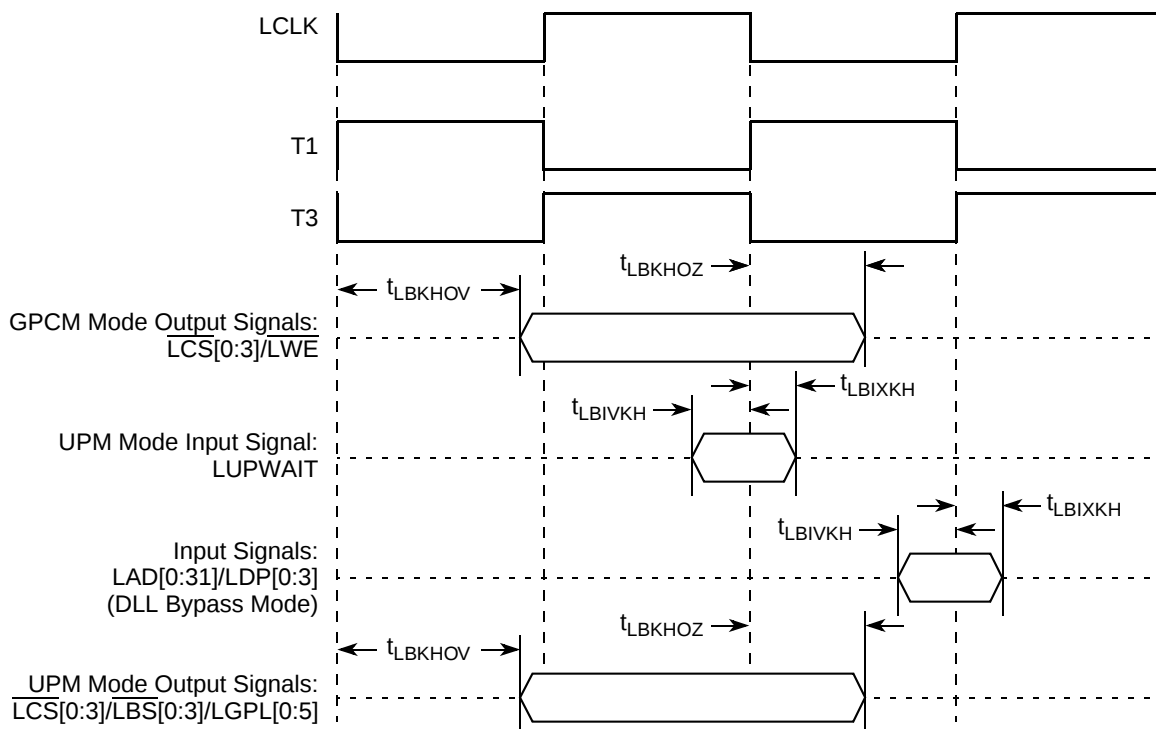


Figure 26. Local Bus Signals, GPCM/UPM Signals for LCRR[CLKDIV] = 2 (DLL Bypass Mode)

JTAG AC Electrical Characteristics

This figure provides the AC test load for TDO and the boundary-scan outputs of the device.

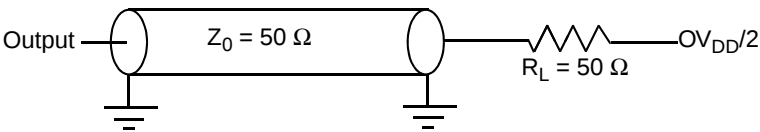


Figure 29. AC Test Load for the JTAG Interface

This figure provides the JTAG clock input timing diagram.

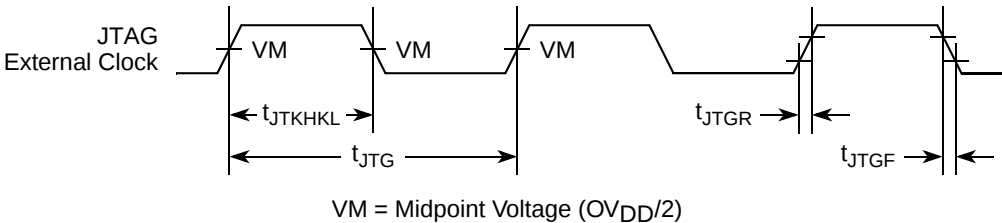


Figure 30. JTAG Clock Input Timing Diagram

This figure provides the $\overline{\text{TRST}}$ timing diagram.

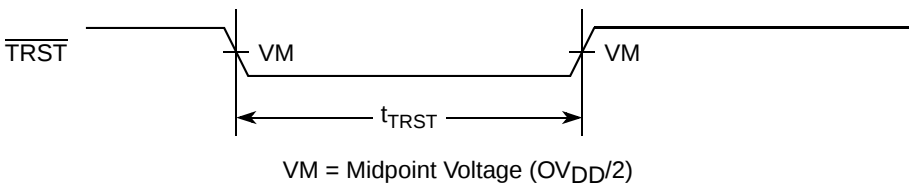


Figure 31. $\overline{\text{TRST}}$ Timing Diagram

This figure provides the boundary-scan timing diagram.

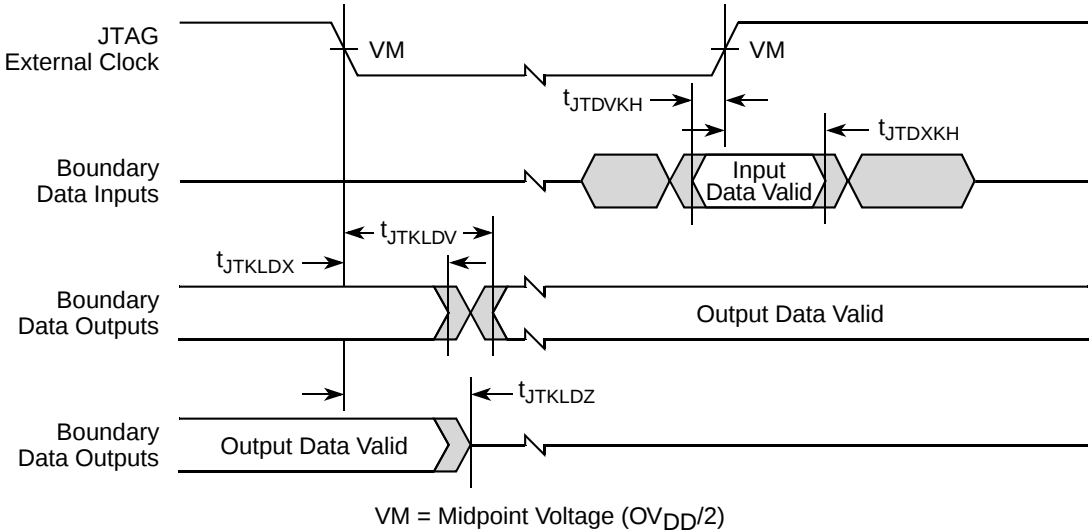


Figure 32. Boundary-Scan Timing Diagram

13.2 Timers AC Timing Specifications

This table provides the timer input and output AC timing specifications.

Table 50. Timers Input AC Timing Specifications¹

Characteristic	Symbol ²	Typ	Unit
Timers inputs—minimum pulse width	t_{TIWID}	20	ns

Notes:

- Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of CLKIN. Timings are measured at the pin.
- Timers inputs and outputs are asynchronous to any visible clock. Timers outputs should be synchronized before use by any external synchronous logic. Timers inputs are required to be valid for at least t_{TIWID} ns to ensure proper operation.

This figure provides the AC test load for the timers.

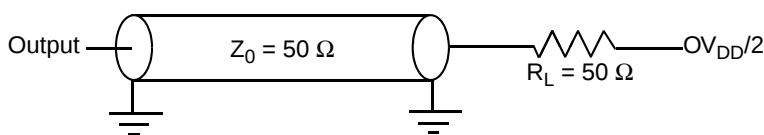


Figure 39. Timers AC Test Load

14 GPIO

This section describes the DC and AC electrical specifications for the GPIO of the MPC8360E/58E.

14.1 GPIO DC Electrical Characteristics

This table provides the DC electrical characteristics for the device GPIO.

Table 51. GPIO DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit	Notes
Output high voltage	V_{OH}	$I_{OH} = -6.0$ mA	2.4	—	V	1
Output low voltage	V_{OL}	$I_{OL} = 6.0$ mA	—	0.5	V	1
Output low voltage	V_{OL}	$I_{OL} = 3.2$ mA	—	0.4	V	1
Input high voltage	V_{IH}	—	2.0	$OV_{DD} + 0.3$	V	1
Input low voltage	V_{IL}	—	-0.3	0.8	V	—
Input current	I_{IN}	$0\text{ V} \leq V_{IN} \leq OV_{DD}$	—	± 10	μA	—

Note:

- This specification applies when operating from 3.3-V supply.

Table 66. MPC8360E TBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
No Connect				
NC	AM20, AU19	—	—	—

Notes:

1. This pin is an open drain signal. A weak pull-up resistor (1 k Ω) should be placed on this pin to OV_{DD}.
2. This pin is an open drain signal. A weak pull-up resistor (2–10 k Ω) should be placed on this pin to OV_{DD}.
3. This output is actively driven during reset rather than being three-stated during reset.
4. These JTAG pins have weak internal pull-up P-FETs that are always enabled.
5. This pin should have a weak pull up if the chip is in PCI host mode. Follow PCI specifications recommendation.
6. These are On Die Termination pins, used to control DDR2 memories internal termination resistance.
7. This pin must always be tied to GND.
8. This pin must always be left not connected.
9. Refer to *MPC8360E PowerQUICC II Pro Integrated Communications Processor Reference Manual* section on “RGMII Pins,” for information about the two UCC2 Ethernet interface options.
10. It is recommended that MDIC0 be tied to GND using an 18.2 Ω resistor and MDIC1 be tied to DDR power using an 18.2 Ω resistor for DDR2.

This table shows the pin list of the MPC8358E TBGA package.

Table 67. MPC8358E TBGA Pinout Listing

Signal	Package Pin Number	Pin Type	Power Supply	Notes
DDR SDRAM Memory Controller Interface				
MEMC1_MDQ[0:63]	AJ34, AK33, AL33, AL35, AJ33, AK34, AK32, AM36, AN37, AN35, AR34, AT34, AP37, AP36, AR36, AT35, AP34, AR32, AP32, AM31, AN33, AM34, AM33, AM30, AP31, AM27, AR30, AT32, AN29, AP29, AN27, AR29, AN8, AN7, AM8, AM6, AP9, AN9, AT7, AP7, AU6, AP6, AR4, AR3, AT6, AT5, AR5, AT3, AP4, AM5, AP3, AN3, AN5, AL5, AN4, AM2, AL2, AH5, AK3, AJ2, AJ3, AH4, AK4, AH3	I/O	GV _{DD}	—
MEMC_MECC[0:4]/MSRCID[0:4]	AP24, AN22, AM19, AN19, AM24	I/O	GV _{DD}	—
MEMC_MECC[5]/MDVAL	AM23	I/O	GV _{DD}	—
MEMC_MECC[6:7]	AM22, AN18	I/O	GV _{DD}	—
MEMC_MDM[0:8]	AL36, AN34, AP33, AN28, AT9, AU4, AM3, AJ6, AP27	O	GV _{DD}	—
MEMC_MDQS[0:8]	AK35, AP35, AN31, AM26, AT8, AU3, AL4, AJ5, AP26	I/O	GV _{DD}	—
MEMC_MBA[0:1]	AU29, AU30	O	GV _{DD}	—
MEMC_MBA[2]	AT30	O	GV _{DD}	—
MEMC_MA[0:14]	AU21, AP22, AP21, AT21, AU25, AU26, AT23, AR26, AU24, AR23, AR28, AU23, AR22, AU20, AR18	O	GV _{DD}	—
MEMC_MODT[0:3]	AG33, AJ36, AT1, AK2	O	GV _{DD}	6

Table 67. MPC8358E TBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
PCI_MODE	D36	I	OV _{DD}	—
M66EN/CE_PF[4]	B37	I/O	OV _{DD}	—
Local Bus Controller Interface				
LAD[0:31]	N32, N33, N35, N36, P37, P32, P34, R36, R35, R34, R33, T37, T35, T34, T33, U37, T32, U36, U34, V36, V35, W37, W35, V33, V32, W34, Y36, W32, AA37, Y33, AA35, AA34	I/O	OV _{DD}	—
LDP[0]/CKSTOP_OUT	AB37	I/O	OV _{DD}	—
LDP[1]/CKSTOP_IN	AB36	I/O	OV _{DD}	—
LDP[2]/LCS[6]	AB35	I/O	OV _{DD}	—
LDP[3]/LCS[7]	AA33	I/O	OV _{DD}	—
LA[27:31]	AC37, AA32, AC36, AC34, AD36	O	OV _{DD}	—
LCS[0:5]	AD33, AG37, AF34, AE33, AD32, AH37	O	OV _{DD}	—
LWE[0:3]/LSDDQM[0:3]/LBS[0:3]	AG35, AG34, AH36, AE32	O	OV _{DD}	—
LBCTL	AD35	O	OV _{DD}	—
LALE	M37	O	OV _{DD}	—
LGPL0/LSDA10/cfg_reset_source0	AB32	I/O	OV _{DD}	—
LGPL1/LSDWE/cfg_reset_source1	AE37	I/O	OV _{DD}	—
LGPL2/LSDRAS/LOE	AC33	O	OV _{DD}	—
LGPL3/LSDCAS/cfg_reset_source2	AD34	I/O	OV _{DD}	—
LGPL4/LGTA/LUPWAIT/LPBSE	AE35	I/O	OV _{DD}	—
LGPL5/cfg_clkin_div	AF36	I/O	OV _{DD}	—
LCKE	G36	O	OV _{DD}	—
LCLK[0]	J33	O	OV _{DD}	—
LCLK[1]/LCS[6]	J34	O	OV _{DD}	—
LCLK[2]/LCS[7]	G37	O	OV _{DD}	—
LSYNC_OUT	F34	O	OV _{DD}	—
LSYNC_IN	G35	I	OV _{DD}	—
Programmable Interrupt Controller				
MCP_OUT	E34	O	OV _{DD}	2
IRQ0/MCP_IN	C37	I	OV _{DD}	—
IRQ[1]/M1SRCID[4]/M2SRCID[4]/LSRCID[4]	F35	I/O	OV _{DD}	—
IRQ[2]/M1DVAL/M2DVAL/LDVAL	F36	I/O	OV _{DD}	—
IRQ[3]/CORE_SRESET	H34	I/O	OV _{DD}	—

Table 67. MPC8358E TBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
CE_PB[0:27]	AE2, AE1, AD5, AD3, AD2, AC6, AC5, AC4, AC2, AC1, AB5, AB4, AB3, AB1, AA6, AA4, AA2, Y6, Y4, Y3, Y2, Y1, W6, W5, W2, V5, V3, V2	I/O	OV _{DD}	—
CE_PC[0:1]	V1, U6	I/O	OV _{DD}	
CE_PC[2:3]	C16, A15	I/O	LV _{DD} 1	—
CE_PC[4:6]	U4, U3, T6	I/O	OV _{DD}	—
CE_PC[7]	C19	I/O	LV _{DD} 2	—
CE_PC[8:9]	A4, C5	I/O	LV _{DD} 0	—
CE_PC[10:30]	T5, T4, T2, T1, R5, R3, R1, C11, D12, F13, B10, C10, E12, A9, B8, D10, A14, E15, B14, D15, AH2	I/O	OV _{DD}	—
CE_PD[0:27]	E11, D9, C8, F11, A7, E9, C7, A6, F10, B6, D7, E8, B5, A5, C2, E4, F5, B1, D2, G5, D1, E2, H6, F3, E1, F2, G3, H4	I/O	OV _{DD}	—
CE_PE[0:31]	K3, J2, F1, G2, J5, H3, G1, H2, K6, J3, K5, K4, L6, P6, P4, P3, P1, N4, N5, N2, N1, M2, M3, M5, M6, L1, L2, L4, E14, C13, C14, B13	I/O	OV _{DD}	—
CE_PF[0:3]	F14, D13, A12, A11	I/O	OV _{DD}	—
Clocks				
PCI_CLK_OUT[0]/CE_PF[26]	B22	I/O	LV _{DD} 2	—
PCI_CLK_OUT[1:2]/CE_PF[27:28]	D22, A23	I/O	OV _{DD}	—
CLKIN	E37	I	OV _{DD}	—
PCI_CLOCK/PCI_SYNC_IN	M36	I	OV _{DD}	—
PCI_SYNC_OUT/CE_PF[29]	D37	I/O	OV _{DD}	3
JTAG				
TCK	K33	I	OV _{DD}	—
TDI	K34	I	OV _{DD}	4
TDO	H37	O	OV _{DD}	3
TMS	J36	I	OV _{DD}	4
TRST	L32	I	OV _{DD}	4
Test				
TEST	L35	I	OV _{DD}	7
TEST_SEL	AU34	I	GV _{DD}	10
PMC				
QUIESCE	B36	O	OV _{DD}	—
System Control				

Table 67. MPC8358E TBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
$\overline{\text{PORESET}}$	L37	I	OV_{DD}	—
$\overline{\text{HRESET}}$	L36	I/O	OV_{DD}	1
$\overline{\text{SRESET}}$	M33	I/O	OV_{DD}	2
Thermal Management				
THERM0	AP19	I	GV_{DD}	—
THERM1	AT31	I	GV_{DD}	—
Power and Ground Signals				
$\text{AV}_{\text{DD}1}$	K35	Power for LBIU DLL (1.2 V)	$\text{AV}_{\text{DD}1}$	—
$\text{AV}_{\text{DD}2}$	K36	Power for CE PLL (1.2 V)	$\text{AV}_{\text{DD}2}$	—
$\text{AV}_{\text{DD}5}$	AM29	Power for e300 PLL (1.2 V)	$\text{AV}_{\text{DD}5}$	—
$\text{AV}_{\text{DD}6}$	K37	Power for system PLL (1.2 V)	$\text{AV}_{\text{DD}6}$	—
GND	A2, A8, A13, A19, A22, A25, A31, A33, A36, B7, B12, B24, B27, B30, C4, C6, C9, C15, C26, C32, D3, D8, D11, D14, D17, D19, D23, D27, E7, E13, E25, E30, E36, F4, F37, G34, H1, H5, H32, H33, J4, J32, J37, K1, L3, L5, L33, L34, M1, M34, M35, N37, P2, P5, P35, P36, R4, T3, U1, U5, U35, V37, W1, W4, W33, W36, Y34, AA3, AA5, AC3, AC32, AC35, AD1, AD37, AE4, AE34, AE36, AF33, AG4, AG6, AG32, AH35, AJ1, AJ4, AJ32, AJ35, AJ37, AK36, AL3, AL34, AM4, AN6, AN23, AN30, AP8, AP12, AP14, AP16, AP17, AP20, AP25, AR6, AR8, AR9, AR19, AR24, AR31, AR35, AR37, AT4, AT10, AT19, AT20, AT25, AU14, AU22, AU28, AU35	—	—	—
GV_{DD}	AD4, AE3, AF1, AF5, AF35, AF37, AG2, AG36, AH33, AH34, AK5, AM1, AM35, AM37, AN2, AN10, AN11, AN12, AN14, AN32, AN36, AP5, AP23, AP28, AR1, AR7, AR10, AR12, AR21, AR25, AR27, AR33, AT15, AT22, AT28, AT33, AU2, AU5, AU16, AU31, AU36	Power for DDR DRAM I/O voltage (2.5 or 1.8 V)	GV_{DD}	—
$\text{LV}_{\text{DD}0}$	D5, D6	Power for UCC1 Ethernet interface (2.5 V, 3.3 V)	$\text{LV}_{\text{DD}0}$	—

Table 67. MPC8358E TBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
LV _{DD} 1	C17, D16	Power for UCC2 Ethernet interface option 1 (2.5 V, 3.3 V)	LV _{DD} 1	9
LV _{DD} 2	B18, E21	Power for UCC2 Ethernet interface option 2 (2.5 V, 3.3 V)	LV _{DD} 2	9
V _{DD}	C36, D29, D35, E16, F9, F12, F15, F17, F18, F20, F21, F23, F25, F26, F29, F31, F32, F33, G6, J6, K32, M32, N6, P33, R6, R32, U32, V6, Y5, Y32, AB6, AB33, AD6, AF32, AK6, AL6, AM7, AM9, AM10, AM11, AM12, AM13, AM14, AM15, AM18, AM21, AM25, AM28, AM32, AN15, AN21, AN26, AU9, AU17	Power for core (1.2 V)	V _{DD}	—
OV _{DD}	A10, B9, B15, B32, C1, C12, C22, C29, D24, E3, E10, E27, G4, H35, J1, J35, K2, M4, N3, N34, R2, R37, T36, U2, U33, V4, V34, W3, Y35, Y37, AA1, AA36, AB2, AB34	PCI, 10/100 Ethernet, and other standard (3.3 V)	OV _{DD}	—
MVREF1	AN20	I	DDR reference voltage	—
MVREF2	AU32	I	DDR reference voltage	—
SPARE1	B11	I/O	OV _{DD}	8
SPARE3	AH32	—	GV _{DD}	8
SPARE4	AU18	—	GV _{DD}	7
SPARE5	AP1	—	GV _{DD}	8

21 Clocking

This figure shows the internal distribution of clocks within the MPC8360E.

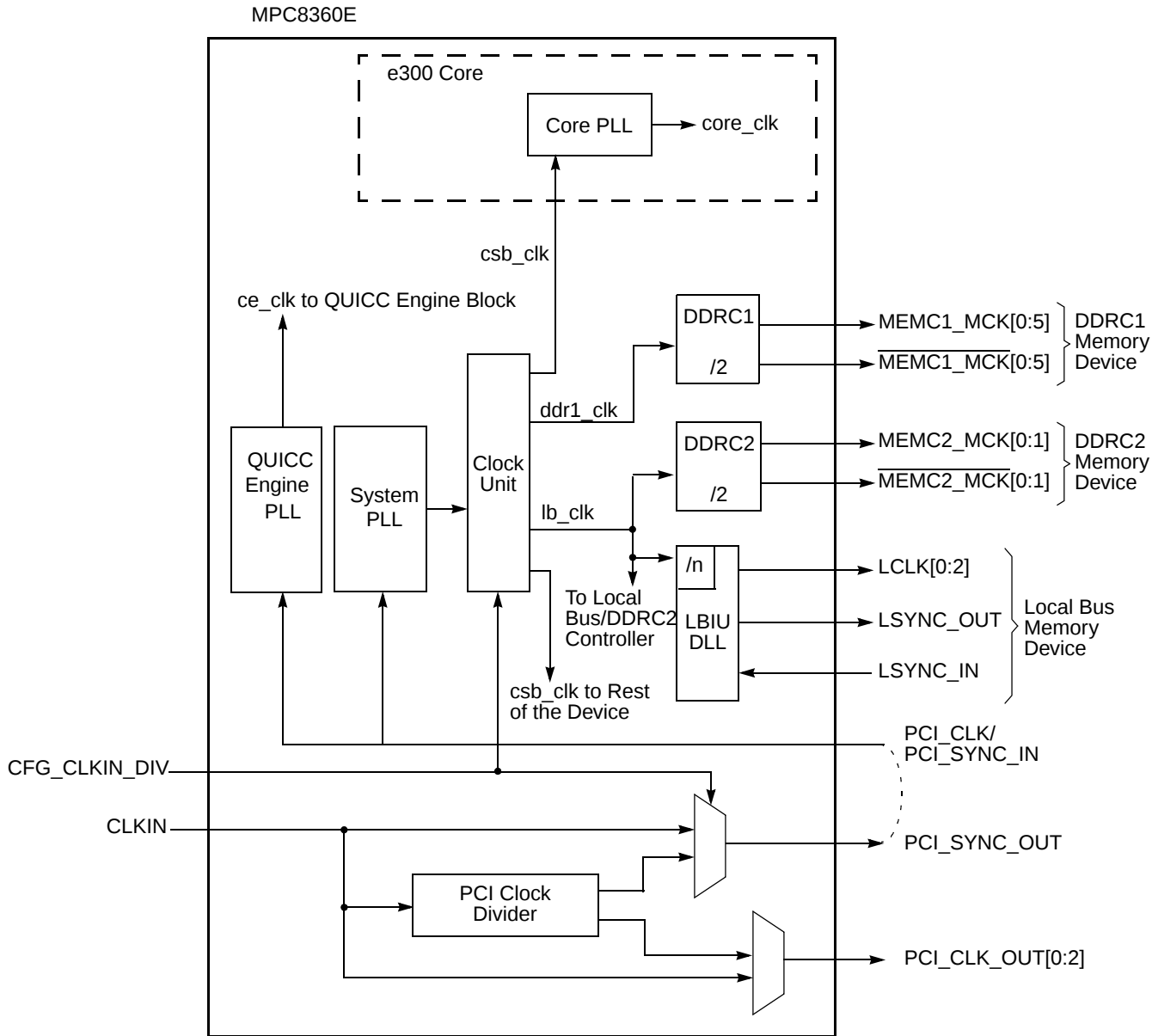


Figure 54. MPC8360E Clock Subsystem

21.2 Core PLL Configuration

RCWL[COREPLL] selects the ratio between the internal coherent system bus clock (*csb_clk*) and the e300 core clock (*core_clk*). This table shows the encodings for RCWL[COREPLL]. COREPLL values not listed in this table should be considered reserved.

Table 73. e300 Core PLL Configuration

RCWL[COREPLL]			<i>core_clk:csb_clk</i> Ratio	VCO divider
0–1	2–5	6		
nn	0000	n	PLL bypassed (PLL off, <i>csb_clk</i> clocks core directly)	PLL bypassed (PLL off, <i>csb_clk</i> clocks core directly)
00	0001	0	1:1	÷2
01	0001	0	1:1	÷4
10	0001	0	1:1	÷8
11	0001	0	1:1	÷8
00	0001	1	1.5:1	÷2
01	0001	1	1.5:1	÷4
10	0001	1	1.5:1	÷8
11	0001	1	1.5:1	÷8
00	0010	0	2:1	÷2
01	0010	0	2:1	÷4
10	0010	0	2:1	÷8
11	0010	0	2:1	÷8
00	0010	1	2.5:1	÷2
01	0010	1	2.5:1	÷4
10	0010	1	2.5:1	÷8
11	0010	1	2.5:1	÷8
00	0011	0	3:1	÷2
01	0011	0	3:1	÷4
10	0011	0	3:1	÷8
11	0011	0	3:1	÷8

NOTE

Core VCO frequency = Core frequency × VCO divider. The VCO divider (RCWL[COREPLL[0:1]]) must be set properly so that the core VCO frequency is in the range of 800–1800 MHz. Having a core frequency below the CSB frequency is not a possible option because the core frequency must be equal to or greater than the CSB frequency.

The QUICC Engine block VCO frequency is derived from the following equations:

$$ce_clk = (\text{primary clock input} \times \text{CEPMF}) \div (1 + \text{CEPDF})$$

$$\text{QE VCO Frequency} = ce_clk \times \text{VCO divider} \times (1 + \text{CEPDF})$$

21.4 Suggested PLL Configurations

To simplify the PLL configurations, the device might be separated into two clock domains. The first domain contains the CSB PLL and the core PLL. The core PLL is connected serially to the CSB PLL, and has the csb_clk as its input clock. The second clock domain has the QUICC Engine block PLL. The clock domains are independent, and each of their PLLs are configured separately. Both of the domains has one common input clock. This table shows suggested PLL configurations for 33 and 66 MHz input clocks and illustrates each of the clock domains separately. Any combination of clock domains setting with same input clock are valid. Refer to [Section 21, “Clocking,”](#) for the appropriate operating frequencies for your device.

Table 76. Suggested PLL Configurations

Conf No. ¹	SPMF	CORE PLL	CEPMF	CEPDF	Input Clock Freq (MHz)	CSB Freq (MHz)	Core Freq (MHz)	QUICC Engine Freq (MHz)	400 (MHz)	533 (MHz)	667 (MHz)
33 MHz CLKIN/PCI_SYNC_IN Options											
s1	0100	0000100	æ	æ	33	133	266	—	∞	∞	∞
s2	0100	0000101	æ	æ	33	133	333	—	∞	∞	∞
s3	0101	0000100	æ	æ	33	166	333	—	∞	∞	∞
s4	0101	0000101	æ	æ	33	166	416	—	—	∞	∞
s5	0110	0000100	æ	æ	33	200	400	—	∞	∞	∞
s6	0110	0000110	æ	æ	33	200	600	—	—	—	∞
s7	0111	0000011	æ	æ	33	233	350	—	∞	∞	∞
s8	0111	0000100	æ	æ	33	233	466	—	—	∞	∞
s9	0111	0000101	æ	æ	33	233	583	—	—	—	∞
s10	1000	0000011	æ	æ	33	266	400	—	∞	∞	∞
s11	1000	0000100	æ	æ	33	266	533	—	—	∞	∞
s12	1000	0000101	æ	æ	33	266	667	—	—	—	∞
s13	1001	0000010	æ	æ	33	300	300	—	∞	∞	∞
s14	1001	0000011	æ	æ	33	300	450	—	—	∞	∞
s15	1001	0000100	æ	æ	33	300	600	—	—	—	∞
s16	1010	0000010	æ	æ	33	333	333	—	∞	∞	∞
s17	1010	0000011	æ	æ	33	333	500	—	—	∞	∞
s18	1010	0000100	æ	æ	33	333	667	—	—	—	∞
c1	æ	æ	01001	0	33	—	—	300	∞	∞	∞
c2	æ	æ	01100	0	33	—	—	400	∞	∞	∞
c3	æ	æ	01110	0	33	—	—	466	—	∞	∞
c4	æ	æ	01111	0	33	—	—	500	—	∞	∞

This table shows heat sinks and junction-to-ambient thermal resistance for TBGA package.

Table 78. Heat Sinks and Junction-to-Ambient Thermal Resistance of TBGA Package

Heat Sink Assuming Thermal Grease	Airflow	35 × 35 mm TBGA
		Junction-to-Ambient Thermal Resistance
AAVID 30 × 30 × 9.4 mm pin fin	Natural convention	10.7
AAVID 30 × 30 × 9.4 mm pin fin	1 m/s	6.2
AAVID 30 × 30 × 9.4 mm pin fin	2 m/s	5.3
AAVID 31 × 35 × 23 mm pin fin	Natural convention	8.1
AAVID 31 × 35 × 23 mm pin fin	1 m/s	4.4
AAVID 31 × 35 × 23 mm pin fin	2 m/s	3.7
Wakefield, 53 × 53 × 25 mm pin fin	Natural convention	5.4
Wakefield, 53 × 53 × 25 mm pin fin	1 m/s	3.2
Wakefield, 53 × 53 × 25 mm pin fin	2 m/s	2.4
MEI, 75 × 85 × 12 no adjacent board, extrusion	Natural convention	6.4
MEI, 75 × 85 × 12 no adjacent board, extrusion	1 m/s	3.8
MEI, 75 × 85 × 12 no adjacent board, extrusion	2 m/s	2.5
MEI, 75 × 85 × 12 mm, adjacent board, 40 mm side bypass	1 m/s	2.8

Accurate thermal design requires thermal modeling of the application environment using computational fluid dynamics software which can model both the conduction cooling and the convection cooling of the air moving through the application. Simplified thermal models of the packages can be assembled using the junction-to-case and junction-to-board thermal resistances listed in the thermal resistance table. More detailed thermal models can be made available on request.

Heat sink vendors include the following:

Aavid Thermalloy 603-224-9988
 80 Commercial St.
 Concord, NH 03301
 Internet: www.aavidthermalloy.com

Alpha Novatech 408-749-7601
 473 Sapena Ct. #15
 Santa Clara, CA 95054
 Internet: www.alphanovatech.com

International Electronic Research Corporation (IERC) 818-842-7277
 413 North Moss St.
 Burbank, CA 91502
 Internet: www.ctscorp.com

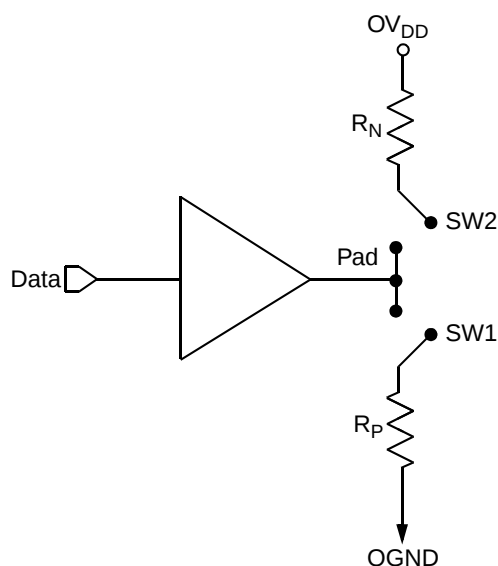


Figure 57. Driver Impedance Measurement

The value of this resistance and the strength of the driver's current source can be found by making two measurements. First, the output voltage is measured while driving logic 1 without an external differential termination resistor. The measured voltage is $V_1 = R_{\text{source}} \times I_{\text{source}}$. Second, the output voltage is measured while driving logic 1 with an external precision differential termination resistor of value R_{term} . The measured voltage is $V_2 = 1/(1/R_1 + 1/R_2) \times I_{\text{source}}$. Solving for the output impedance gives $R_{\text{source}} = R_{\text{term}} \times (V_1/V_2 - 1)$. The drive current is then $I_{\text{source}} = V_1/R_{\text{source}}$.

This table summarizes the signal impedance targets. The driver impedance are targeted at minimum V_{DD} , nominal OV_{DD} , 105° C.

Table 79. Impedance Characteristics

Impedance	Local Bus, Ethernet, DUART, Control, Configuration, Power Management	PCI	DDR DRAM	Symbol	Unit
R_N	42 Target	25 Target	20 Target	Z_0	W
R_P	42 Target	25 Target	20 Target	Z_0	W
Differential	NA	NA	NA	Z_{DIFF}	W

Note: Nominal supply voltages. See Table 1, $T_J = 105^\circ \text{C}$.

23.6 Configuration Pin Muxing

The device provides the user with power-on configuration options that can be set through the use of external pull-up or pull-down resistors of 4.7 k Ω on certain output pins (see customer visible configuration pins). These pins are generally used as output only pins in normal operation.

While $\overline{\text{HRESET}}$ is asserted however, these pins are treated as inputs. The value presented on these pins while $\overline{\text{HRESET}}$ is asserted, is latched when $\overline{\text{HRESET}}$ deasserts, at which time the input receiver is disabled and the I/O circuit takes on its normal function. Careful board layout with stubless connections to these pull-up/pull-down resistors coupled with the large value of the pull-up/pull-down resistor should minimize the disruption of signal quality or speed for output pins thus configured.